



PJU60R980E / PJD60R980E / PJP60R980E / PJF60R980E

600V N-Channel Super Junction MOSFET

Voltage

600 V

Current

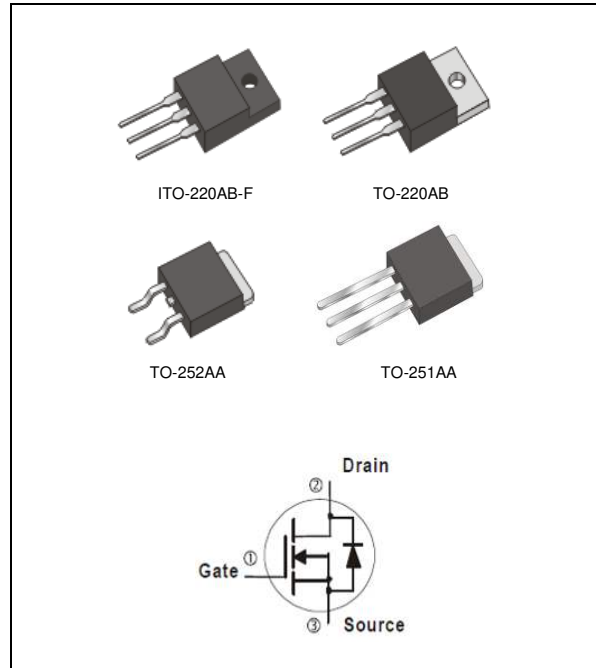
4 A

Features

- $R_{DS(ON)}$, $V_{GS}@10V$, $I_D@1.5A < 0.98\Omega$
- Fast switching speed
- Low on-resistance
- Low Noise
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : TO-251AA, TO-252AA, TO-220AB, ITO-220AB-F
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-251AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-252AA Approx. Weight : 0.0104 ounces, 0.297grams
- TO-220AB Approx. Weight : 0.067 ounces, 1.89 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 2 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TO-251AA	TO-220AB	ITO-220AB-F	TO-252AA	UNITS	
Drain-Source Voltage	V_{DS}	600				V	
Gate-Source Voltage	V_{GS}	± 20					
Continuous Drain Current (Note 4)	I_D	$T_C=25^\circ\text{C}$	4			A	
		$T_C=100^\circ\text{C}$	2.2				
Pulsed Drain Current (Note 1)	I_{DM}	8					
Power Dissipation (Note 3)	P_D	$T_C=25^\circ\text{C}$	58	58	40	58	W
		$T_C=100^\circ\text{C}$	23	23	16	23	
Continuous Drain Current (Note 4)	I_D	$T_A=25^\circ\text{C}$	0.8				A
		$T_A=70^\circ\text{C}$	0.65				
Power Dissipation	P_D	$T_A=25^\circ\text{C}$	2	2	1.04	2	W
		$T_A=70^\circ\text{C}$	1.3	1.3	0.9	1.3	
Single Pulse Avalanche Energy (Note 6)	E_{AS}	32				mJ	
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55~150				$^\circ\text{C}$	
Typical Thermal Resistance (Note 4,5)	$R_{\theta JC}$	2.16	2.16	3.13	2.16	$^\circ\text{C/W}$	
	$R_{\theta JA}$	62.5	62.5	120	62.5		

- Limited only By Maximum Junction Temperature



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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	600	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2	3.3	4	V
Drain-Source On-State Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=1.5A$	-	0.89	0.98	Ω
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=600V, V_{GS}=0V$	-	-	1	μA
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	-	-	± 100	nA
Diode Forward Voltage	V_{SD}	$I_S=4A, V_{GS}=0V$	-	0.92	1.5	V
Transconductance	G_{FS}	$V_{DS}=10V, I_D=2A$	-	3	-	S
Dynamic (Note 7)						
Total Gate Charge	Q_g	$V_{DS}=300V, I_D=4A,$ $V_{GS}=10V$ (Note 2,3)	-	14.4	-	nC
Gate-Source Charge	Q_{gs}		-	2.1	-	
Gate-Drain Charge	Q_{gd}		-	7.8	-	
Gate Input Resistance	R_g	$F = 1\text{MHz}$	-	16.7	-	Ω
Input Capacitance	C_{iss}	$V_{DS}=25V, V_{GS}=0V,$ $f=1\text{MHz}$	-	300	-	pF
Output Capacitance	C_{oss}		-	311	-	
Reverse Transfer Capacitance	C_{rss}		-	41.7	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=300V, I_D=2A,$ $R_G=10\Omega$ (Note 2,3)	-	9	-	ns
Turn-On Rise Time	t_r		-	24	-	
Turn-Off Delay Time	$t_{d(off)}$		-	52	-	
Turn-Off Fall Time	t_f		-	26	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I_S	---	-	-	4	A
Maximum Pulsed Drain-Source Diode Forward Current	I_{SM}	---	-	-	8	
Reverse Recovery Time	t_{rr}	$V_{GS}=0V, I_S=4A$	-	266	-	ns
Reverse Recovery Charge	Q_{rr}	$di_f/dt=100A/\mu s$ (Note 2)	-	2.05	-	μC

NOTES :

- Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
- Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ\text{C}$. Ratings are based on low frequency and duty cycles to keep initial $T_J=25^\circ\text{C}$.
- The maximum current rating is package limited.
- TO-252AA and TO-251AA mounted on a 1 inch² with 2oz. square pad of copper.
- $L=100\text{mH}$, $I_{AS}=0.8A$, $V_{DD}=50V$, $R_G=25\text{ohm}$, Starting $T_J=25^\circ\text{C}$.
- Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

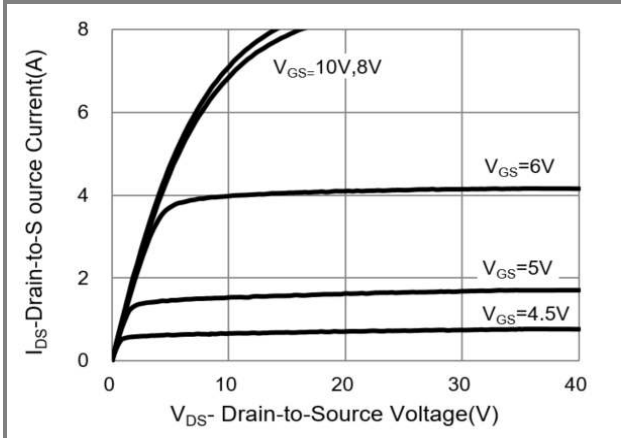


Fig.1 Output Characteristics

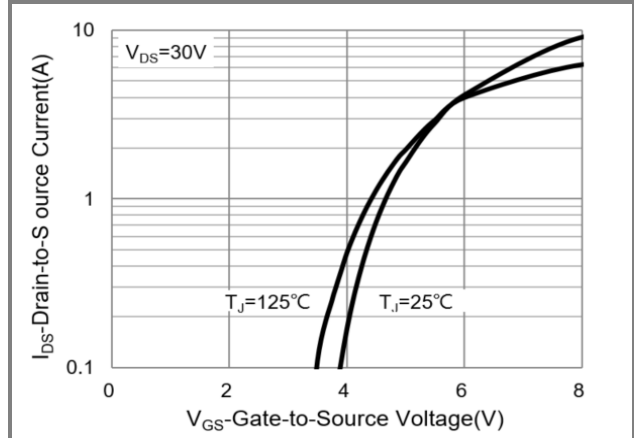


Fig.2 Transfer Characteristics

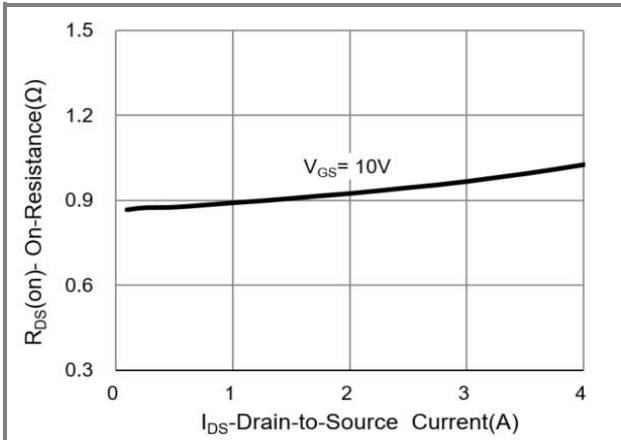


Fig.3 On-Resistance vs. Drain Current

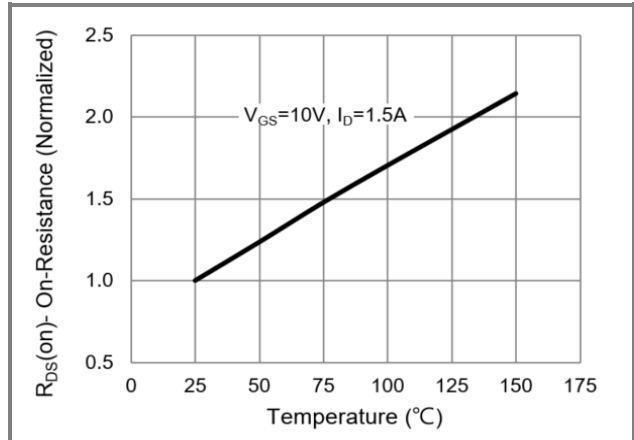


Fig.4 On-Resistance vs. Junction Temperature

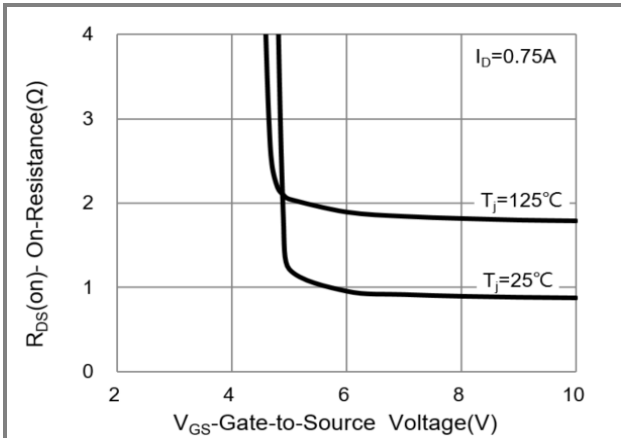


Fig.5 On-Resistance Variation with VGS

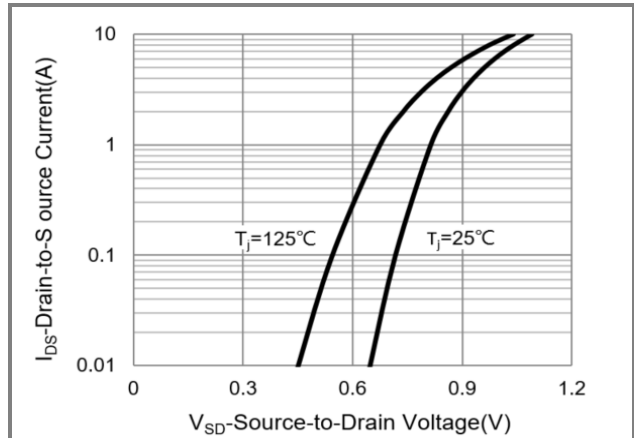


Fig.6 Source-Drain Diode Forward Voltage



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TYPICAL CHARACTERISTIC CURVES

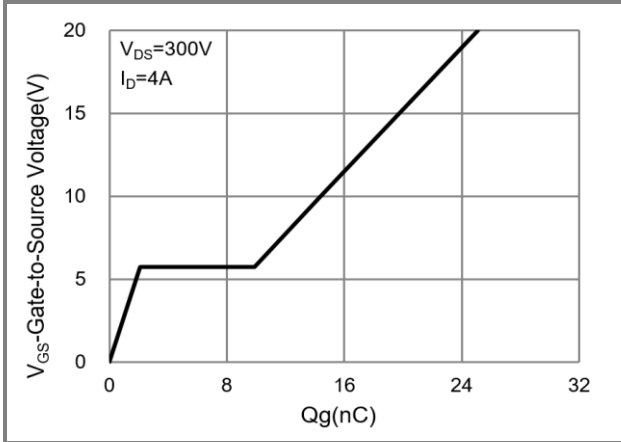


Fig.7 Gate-Charge Characteristics

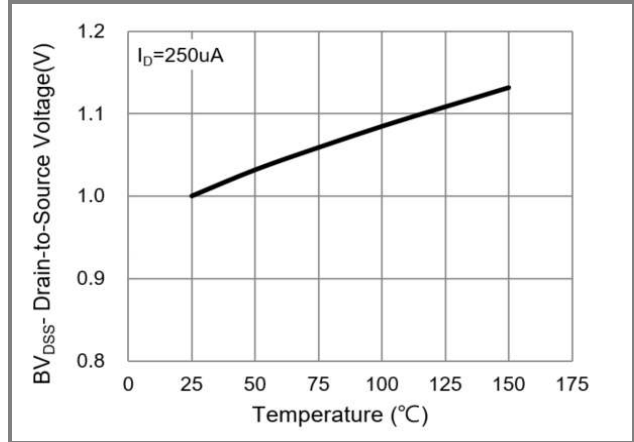


Fig.8 Breakdown Voltage Variation vs. Temperature

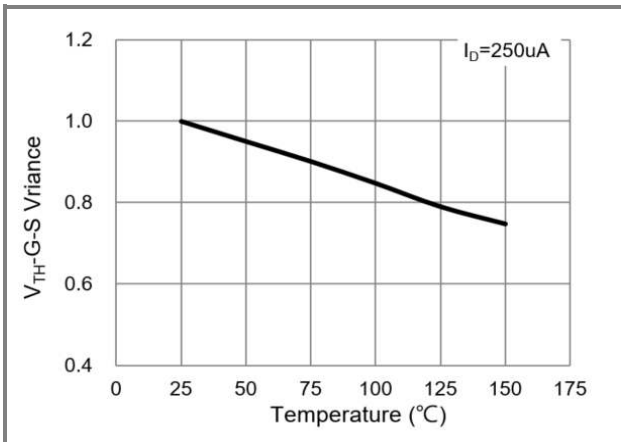


Fig.9 Threshold Voltage Variation with Temperature

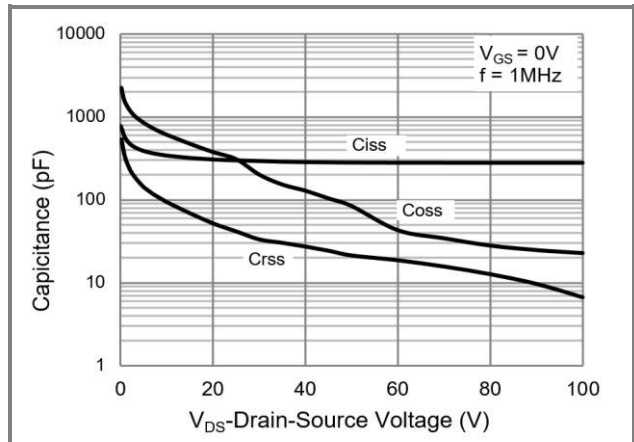


Fig.10 Capacitance vs. Drain-Source Voltage

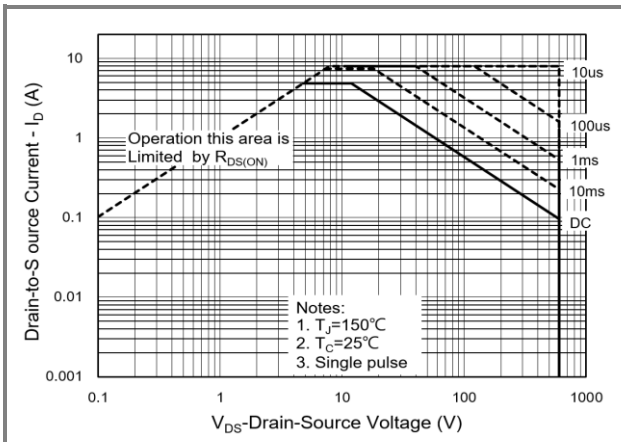


Fig.11 PJU/PJD Maximum Safe Operating Area

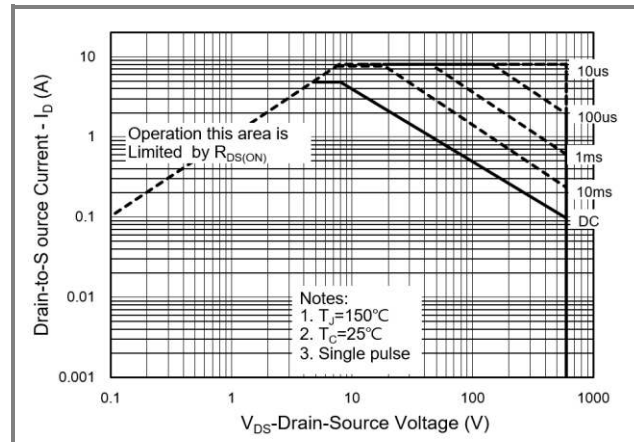


Fig.12 PJP Maximum Safe Operating Area



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TYPICAL CHARACTERISTIC CURVES

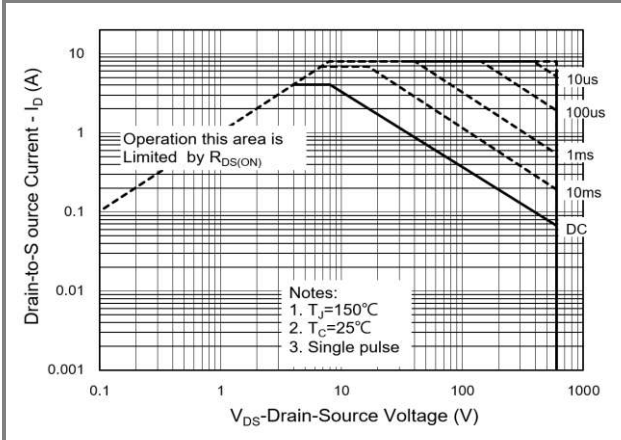


Fig.13 PJF Maximum Safe Operating Area

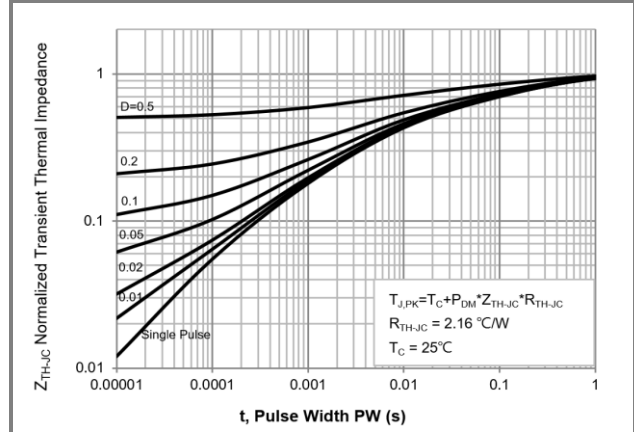


Fig.14 PJU/D Normalized Transient Thermal Impedance

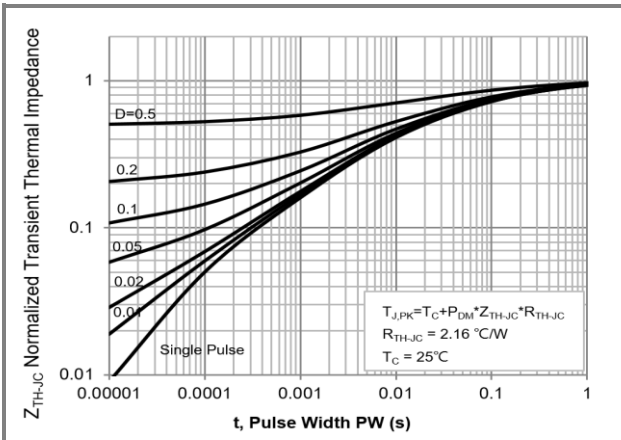


Fig.15 PJP Normalized Transient Thermal Impedance

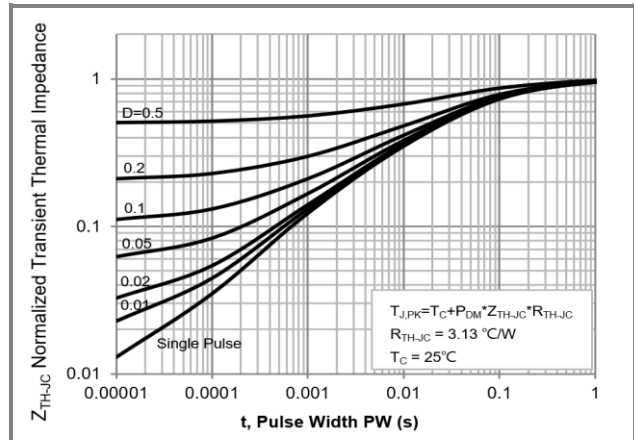


Fig.16 PJF Normalized Transient Thermal Impedance

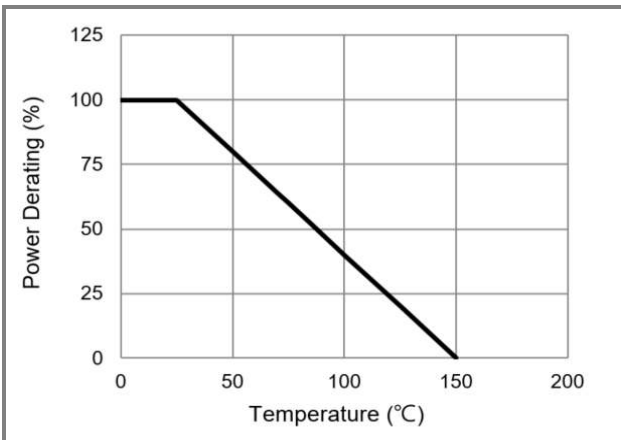
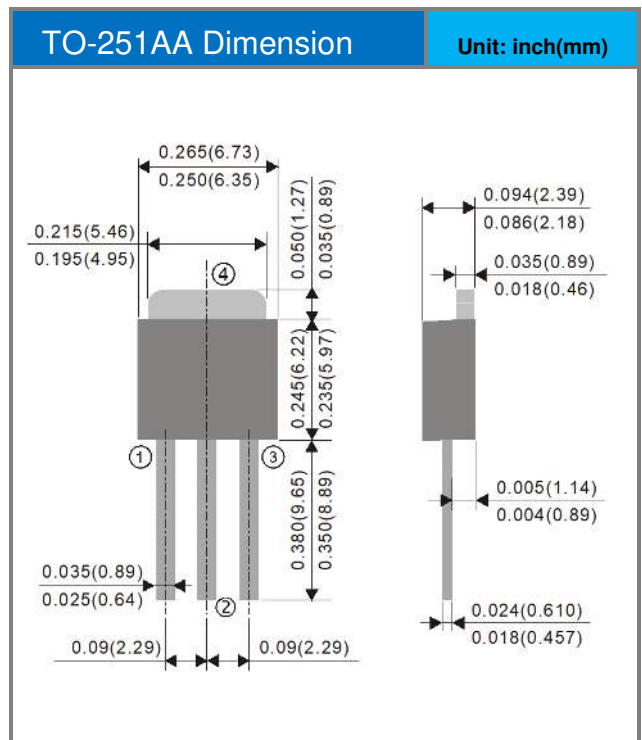
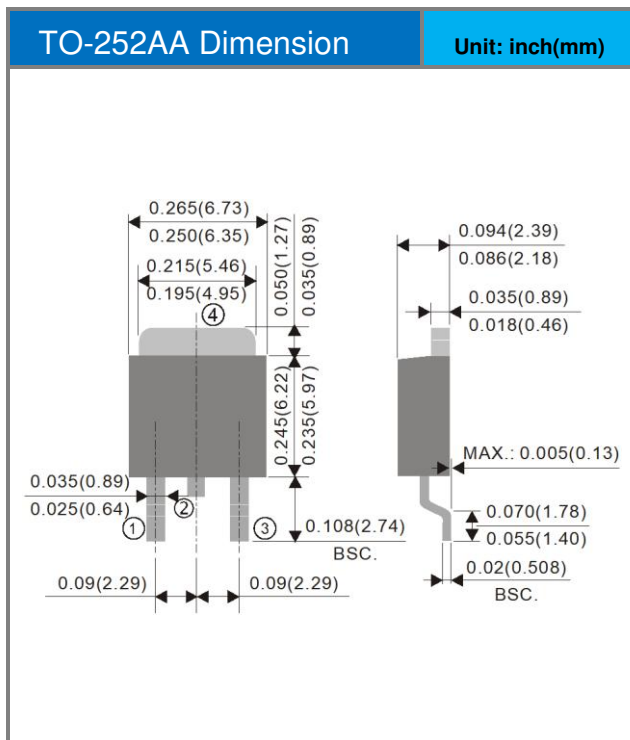
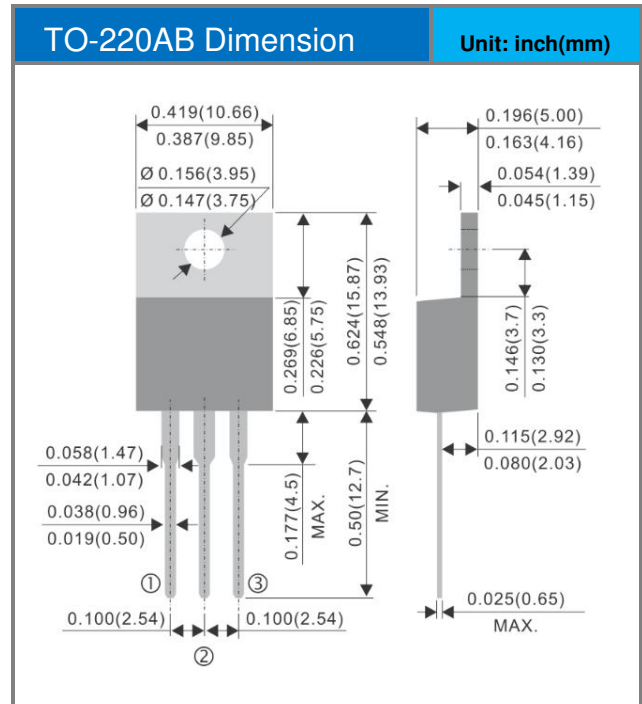
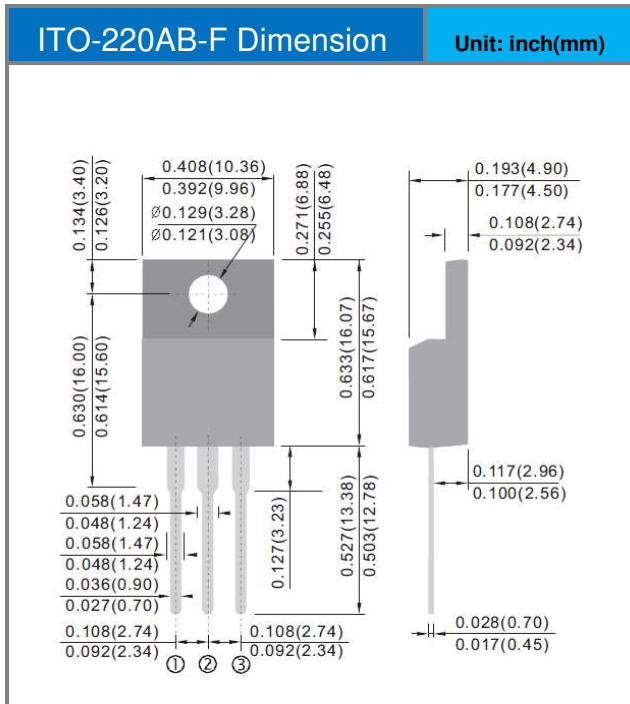


Fig.17 Total Power Dissipation



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Packaging Information





PJU60R980E / PJD60R980E / PJP60R980E / PJF60R980E

Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJU60R980E_T0_00001	TO-251AA	80pcs / Tube	60R980E	Halogen free
PJD60R980E_L2_00001	TO-252AA	3,000pcs / 13" reel	60R980E	Halogen free
PJP60R980E_T0_00001	TO-220AB	50pcs / Tube	60R980E	Halogen free
PJF60R980E_T0_00001	ITO-220AB-F	50pcs / Tube	60R980E	Halogen free



PJU60R980E / PJD60R980E / PJP60R980E / PJF60R980E

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